USA Model



STEREO POWER AMPLIFIER

SPECIFICATIONS

GENERAL

System:

Phase-linear dc stereo amplifier in

direct-coupling V-FET

pure-complementary symmetry circuit

Power requirements:

120 V ac, 60 Hz

Power consumption:

260 W

AC outlet:

1 unswitched, 200 W

Dimensions:

440 (w) \times 170 (h) \times 410 (d) mm $17\frac{3}{8}$ (w) x $6\frac{3}{4}$ (h) x $16\frac{1}{8}$ (d) inches

Weight:

19 kg (41 lb 14 oz), net

23 kg (50 lb 11 oz), in shipping carton

Power bandwidth:

 $5 \, \text{Hz} \sim 50 \, \text{kHz}$

(IHF) Harmonic distortion:

0.1 % at rated output

0.05 % at 1 W output

IM distortion: $(60 \, Hz : 7 \, kHz = 4 : 1)$

0.1 % at rated output 0.05 % at 1 W output

Damping factor:

200 (8 Ω , at 1 kHz, at

SPEAKER DIRECT terminal)

Residual noise:

Frequency response: (at 1 W output)

20 Hz \sim 100 kHz $^{+~0}_{-~3}$ dB (NOR MAL) DC \sim 100 kHz $^{+~0}_{-~1}$ dB (TEST)

Inputs:

Sensitivity 1.0 V RMS (forrated output)

Impedance: 50 k Ω

POWER AMPLIFIER SECTION

Continuous RMS power output: (rated output)

(less than 0.1 % THD)

110 W + 110 W/8 Ω 110 W + 110 W/4 Ω at 1 kHz, both channels

driven simultaneously 100 W + 100 W/8 Ω at $20\,\mathrm{Hz}\,{\sim}\,20\,\mathrm{kHz}$, both

channels driven simultaneously

OPTICAL PEAK PROGRAM METER

Frequency response:

 $30 \, \text{Hz} \sim 30 \, \text{kHz} \, \frac{1}{2} \, \frac{0}{3} \, \text{dB}$

Measuring range:

 $1\sim200\,W$

(METER SENSITIVITY set to "1")

 $0.1 \sim 20 \, \text{W}$

(METER SENSITIVITY set to "1/10")



SERVICING NOTES

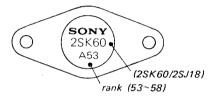
1. Apply the rated ac line voltage to the set directly. Do not increase the voltage gradually by using a variable transformer or other such instrument: this will cause a V-FET failure.

2. V-FET Replacement

TAN-8550 uses six V-FETs (2SK60...3 pcs, 2SJ18...3 pcs) in each channel of its power amplifier. Both 2SK60 and 2SJ18 are divided into six ranks according to their Vsgo (gatesource voltage) and Vp (cut-off voltage). The bias resistors of the V-FET differ from a rank to a rank, and it is necessary to use the same rank of V-FETs in the same channel.

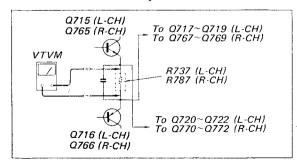
If you cannot obtain the same rank of V-FET as the one used in the repairing set, replace all six V-FETs. At the same time, replace the bias resistors according to the table given at right.

Rank of	Bias Resistors			
2SK60 2SJ18	R725, R775	R731, R781 R732, R782		
53	33 kΩ	1.8 kΩ		
54	33 kΩ	1.5 kΩ		
55	33 kΩ	1.2 kΩ		
56	30 kΩ	1.0 kΩ		
57	30 kΩ	1.0 kΩ		
58	30 kΩ	820 Ω		

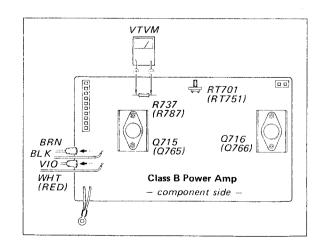


3. After the replacement of V-FET, carry out the following check to avoid further occurance of V-FET failure.

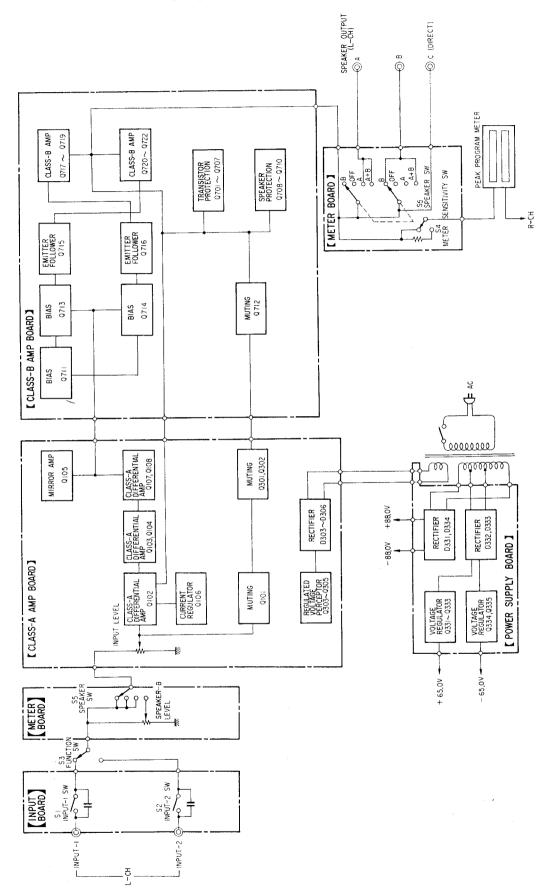
- 1) Turn off the power of TAN-8550.
- 2) Remove the heat sink duct.
- Disconnect the brown and the violet lead wires from the pins on the CLASS B POWER AMP BOARD. See the figure at bottom right.
- 4) Turn on the power and check the voltage across R737 (L-CH)/R787 (R-CH). If the reading does not agree with the value given in the table at right, try adjusting RT701 (L-CH)/RT751 (R-CH).
- 5) If adjusting RT701/RT751 still does not give correct reading, check Q713 ~ Q716 (L-CH)/Q763 ~ Q766 (R-CH). Failure of these transistors will cause V-FET failure.
- 6) After the check, turn off the power of the set and put back the two lead wires mentioned in step 3.



Rank of 2SK60 2SJ18 used in the set	Voltage drop across R737 (L-CH) R787 (R-CH)
53	18.8 ∼ 23.8 V
54	23.8 ∼ 28.8 V
55	28.8 ∼ 33.8 V
56	33.8 ∼ 38.8 V
57 .	38.8 ~ 43.8 V
58	43.8 ∼ 48.8 V

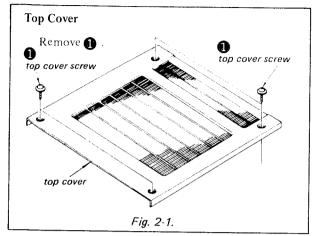


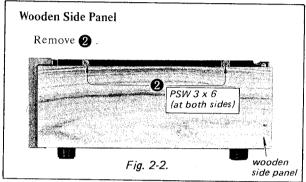
SECTION 1 BLOCK DIAGRAM

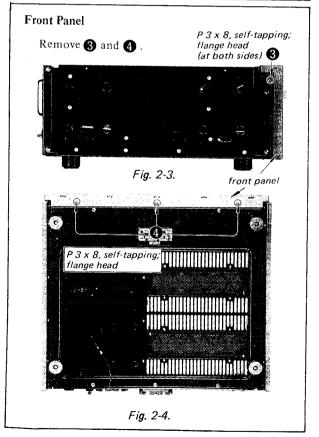


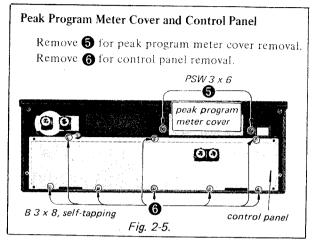
SECTION 2 DISASSEMBLY AND REPLACEMENT

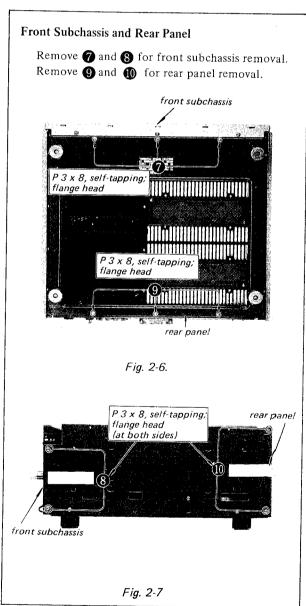
2-1. PANELS REMOVAL











2-2. CIRCUIT BOARD REMOVAL AND V-FET REPLACEMENT

Note: Be careful with the position and the direction of the connectors when reinstalling them to the circuit boards. See Fig. 2-8.

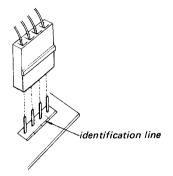
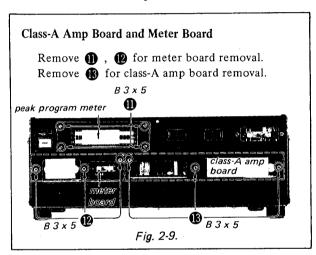
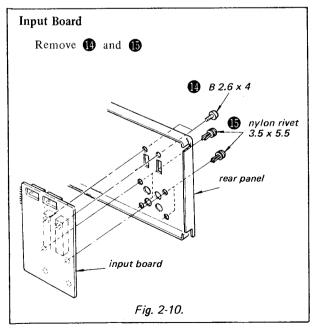
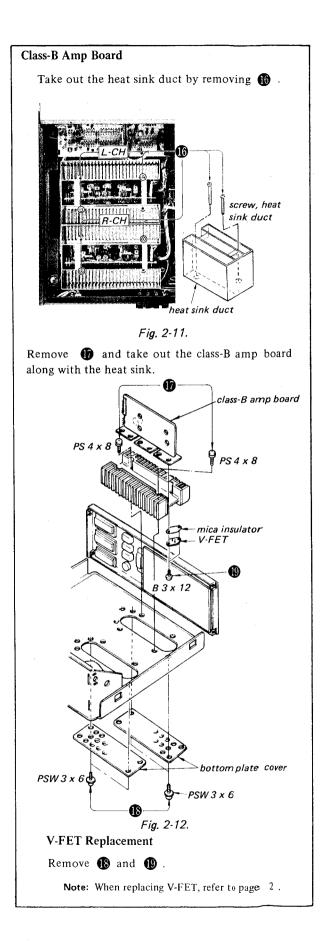


Fig. 2-8.







SECTION 3 ADJUSTMENTS

Note: Allow about five minutes for warm-up.

3-1. LAMP VOLTAGE ADJUSTMENT

Class-A Amp Board

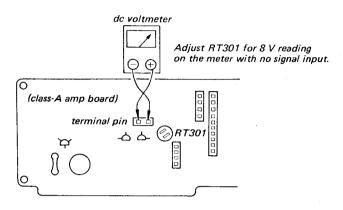


Fig. 3-1.

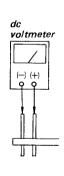
3-2. DC BALANCE AND BIAS ADJUSTMENT

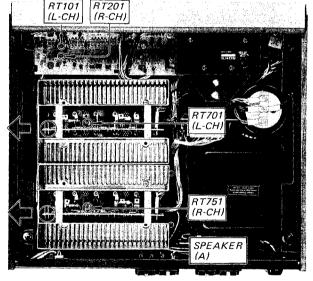
Note: 1. Apply the rated ac line voltage to the set directly. Do not increase the voltage gradually by using a variable transformer or other such instruments: this will cause a V-FET failure.

2. Alternately repeat the two adjustments two or three times.

DC Bias Adjustment

Adjust RT701 (L-CH) and RT751 (R-CH) for 125 mV dc with no signal input.





DC Balance Adjustment

Adjust RT101 (L-CH) and RT201 (R-CH) for 0 V dc with no signal input.

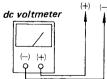


Fig. 3-2.

3-3. PEAK PROGRAM METER ADJUSTMENT AND CHECK

Test Setup:

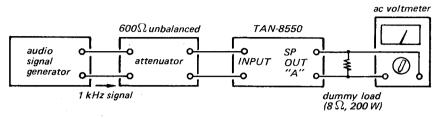


Fig. 3-3.

Procedure:

- 1. Adjust the attenuator for 28.3 V (100 W) reading on the ac voltmeter.
- 2. Set the METER SENSITIVITY switch to "x1", and adjust RT181 (L-CH) and RT281 (R-CH) (See Fig. 3-4) for 100 W reading on the peak program meter.
- 3. Check the following items:

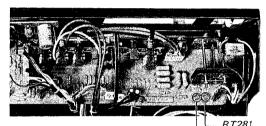
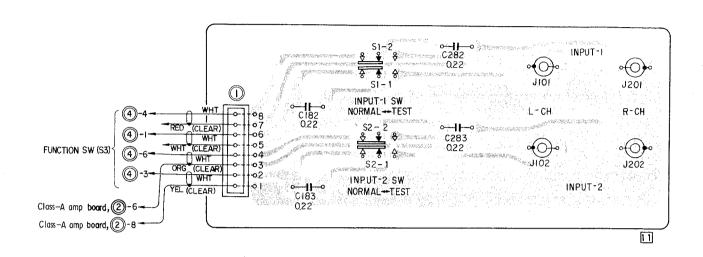


Fig. 3-4. (L-CH)

Step	Attenuator Setting	METER SENSITIVITY Switch Setting	PEAK PROGRAM METER Indication
3-1	Decrease 10 dB from step 2.	x 1	10 W
3-2	Same as step 3-1	x1/10	100 W
3-3	Decrease 10 dB from step 3-2.	x1/10	10 W
3-4	Same as step 3-3	x1	1 W

SECTION 4 DIAGRAMS

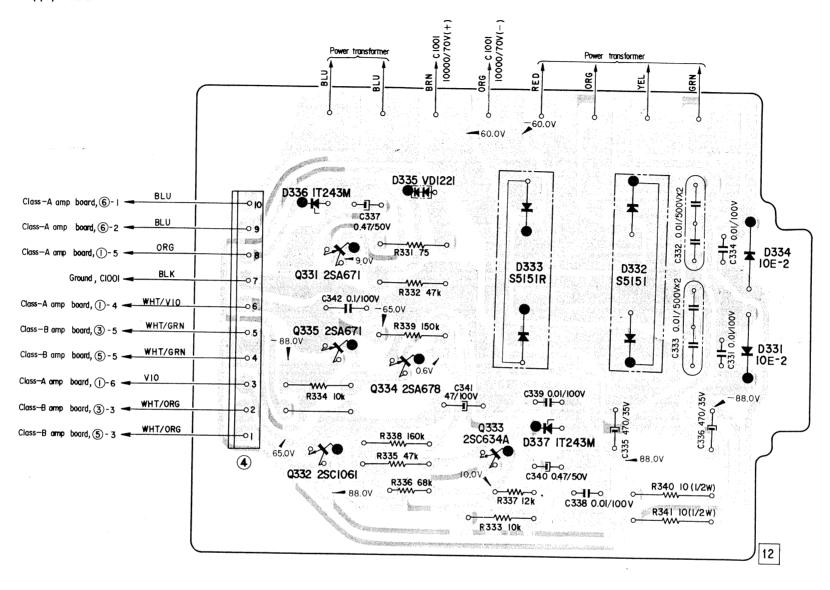
4-1. MOUNTING DIAGRAM — Input Board — — Conductor Side —

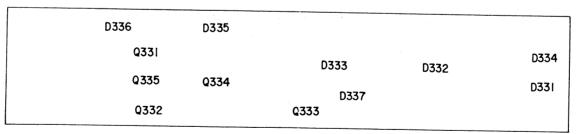


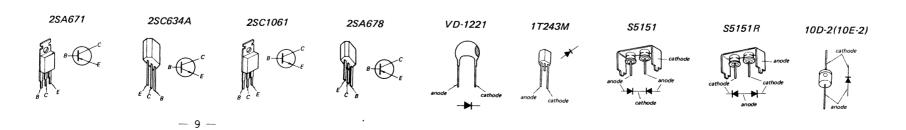


4-2. MOUNTING DIAGRAM -- Power Supply Board -

- Conductor Side -

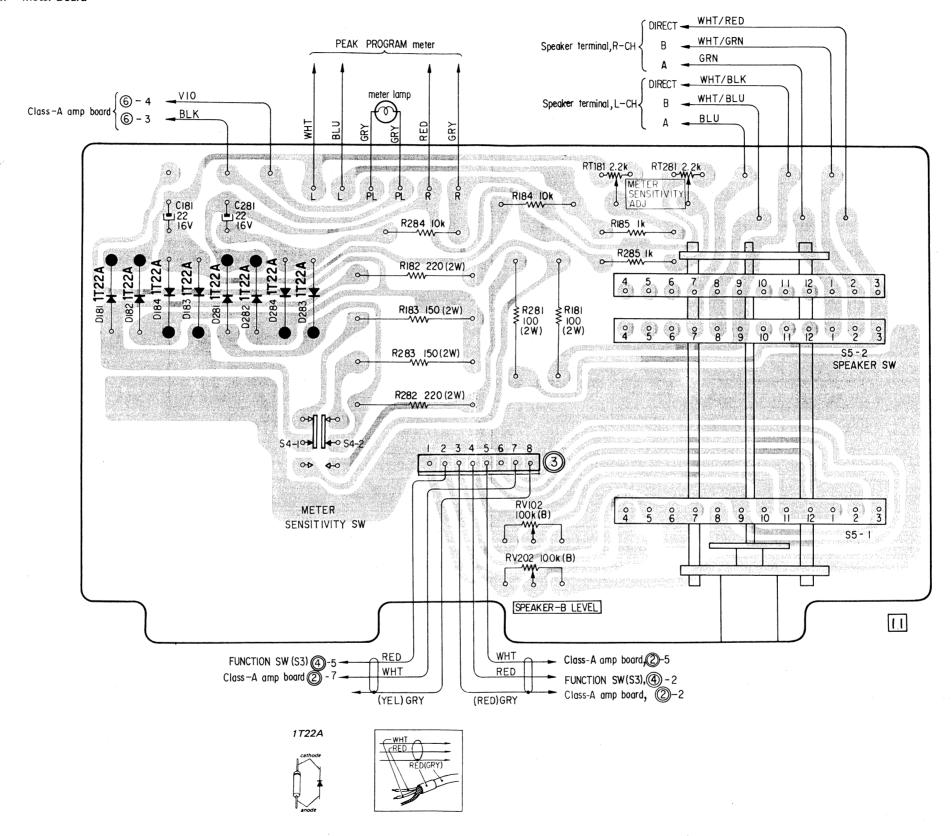




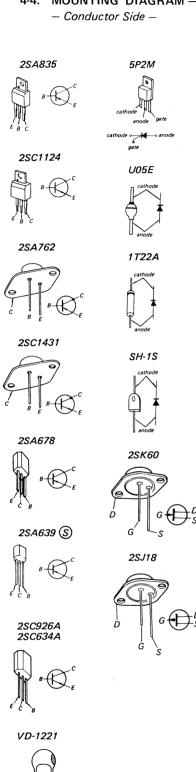


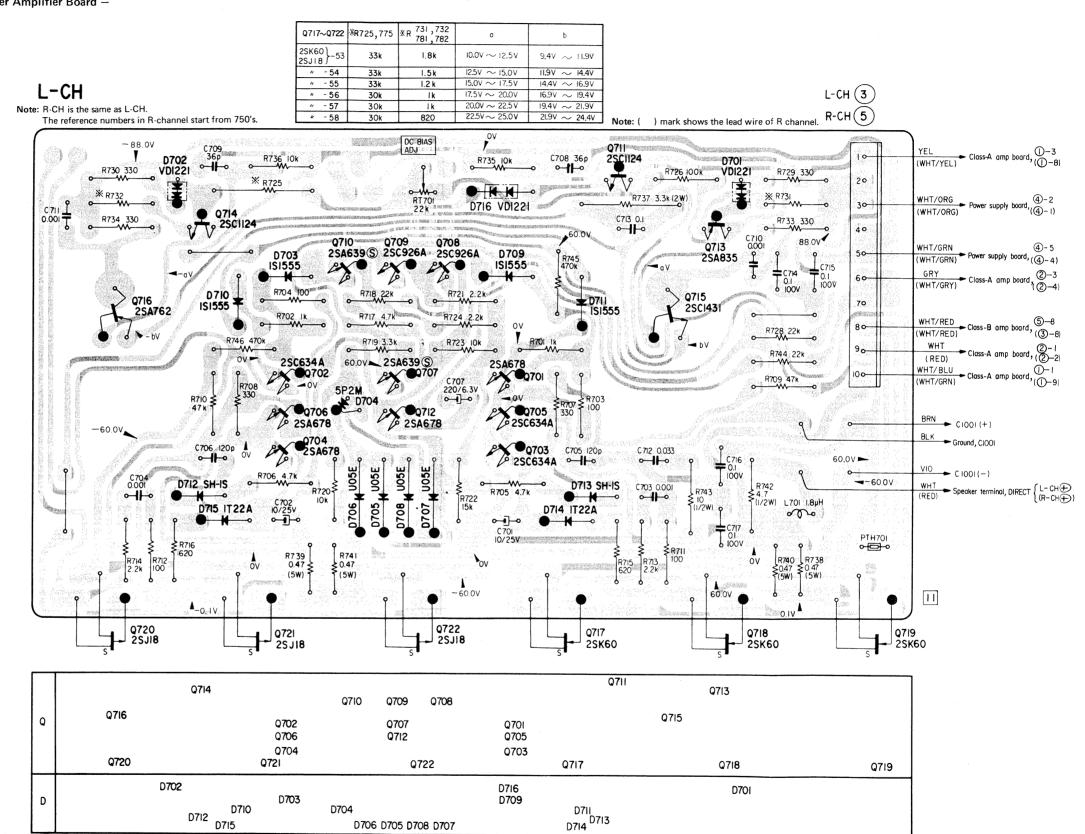
4-3. MOUNTING DIAGRAM - Meter Board -

- Conductor Side -

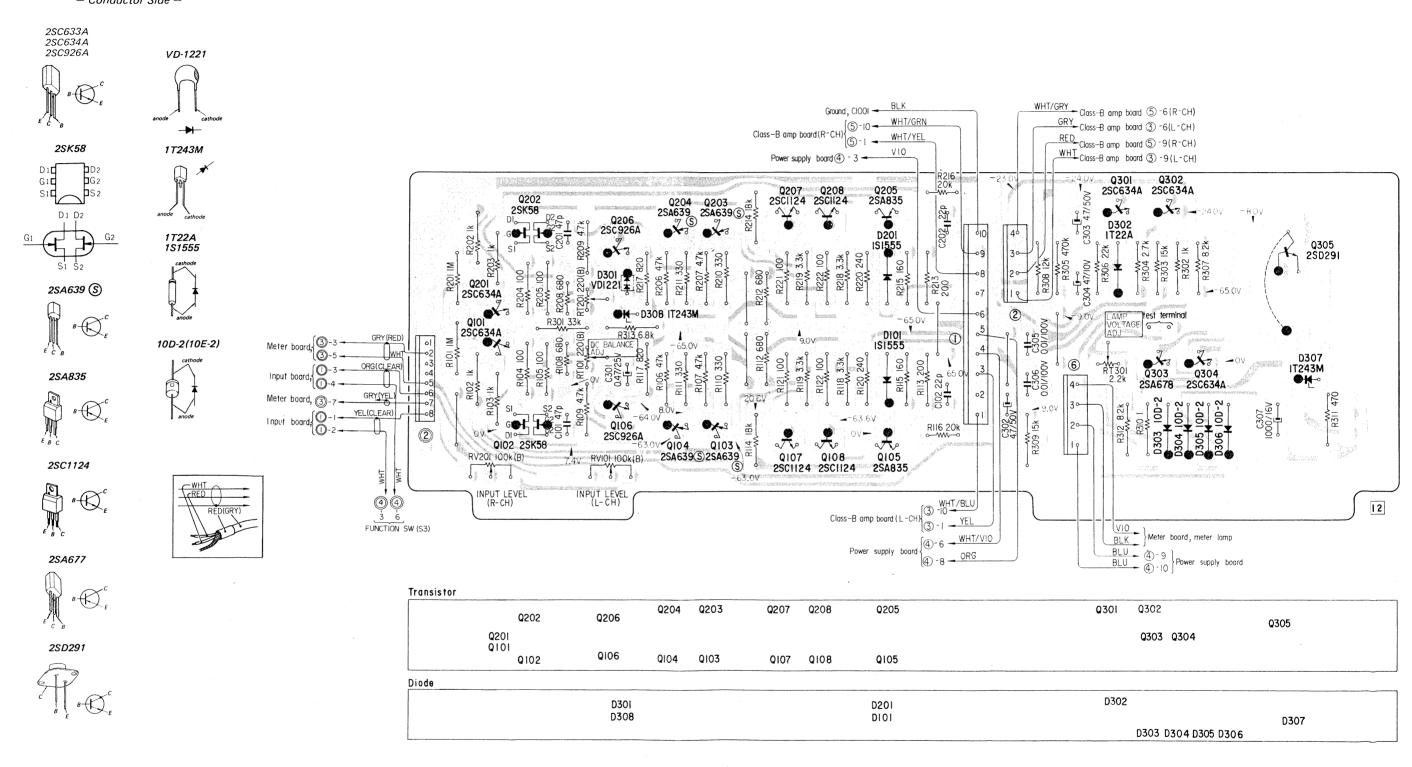


4-4. MOUNTING DIAGRAM - Class-B Power Amplifier Board -

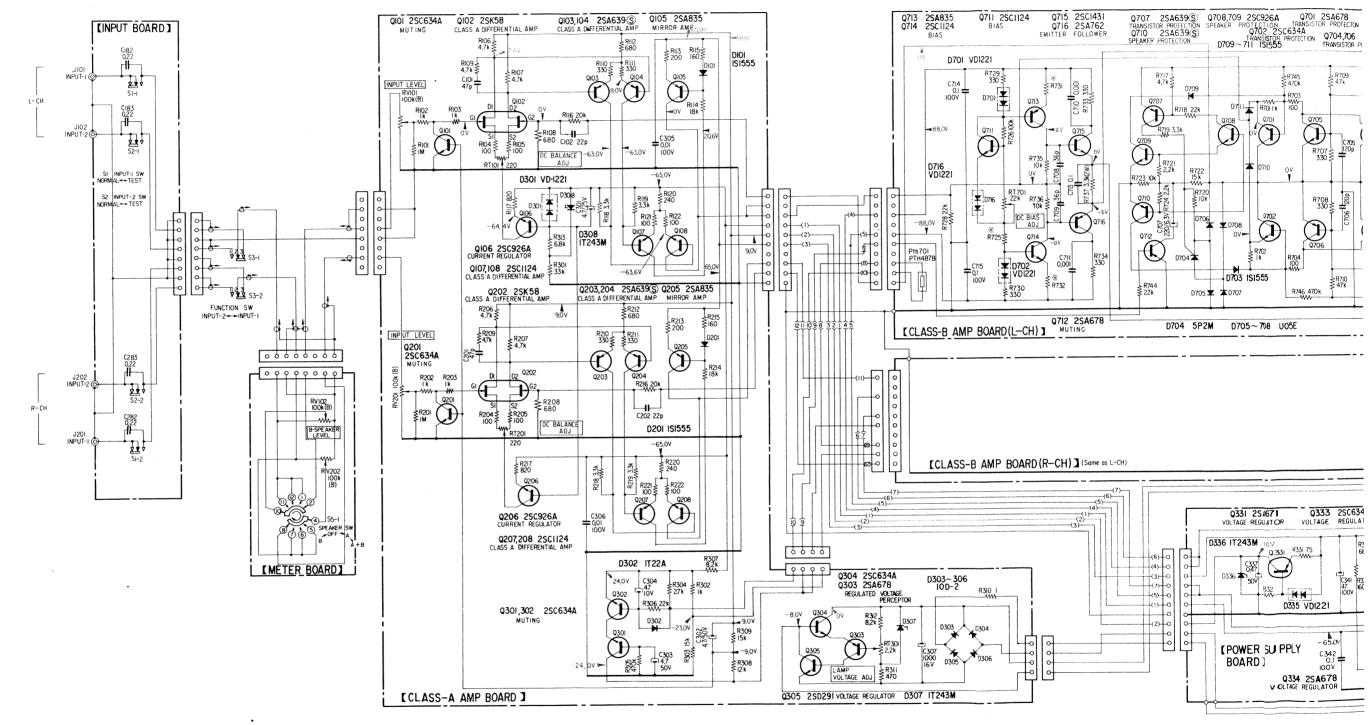




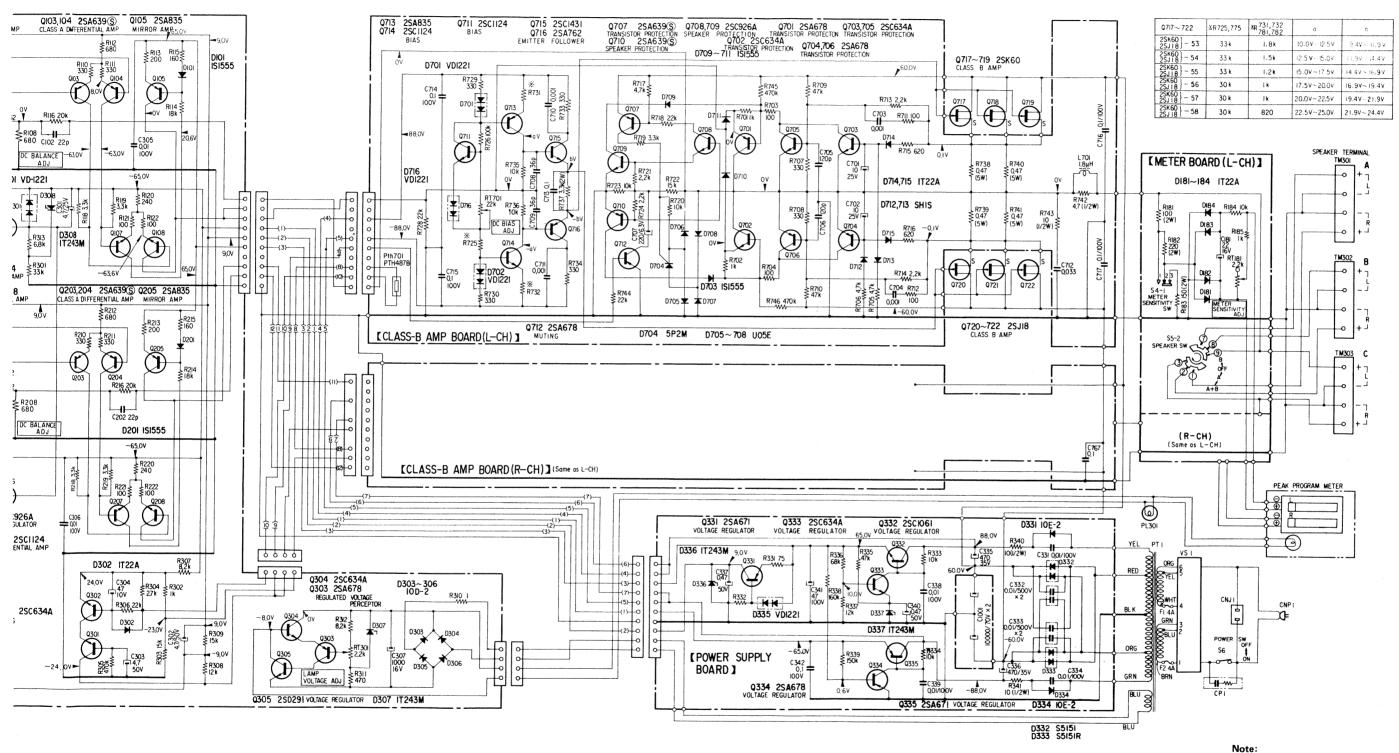
4-5. MOUNTING DIAGRAM - Class-A Power Amplifier Board - - Conductor Side -



4-6. SCHEMATIC DIAGRAM



Ref. No.	Description	Position
 S1	INPUT-1	NORMAL
S2	INPUT-2	NORMAL
S3	FUNCTION	INPUT-1
S4	METER SENSITIVITY	x1
S5	SPEAKER	В
S6	POWER	ON



All resistance values are in ohms. (k = 1,000, M : 1,000 k) All capacitance values are in μ F except as indiated with p, which means $\mu\mu$ F.

All voltages are dc measured with a VOM whichha≤ an input impedance of 20 k ohms/volt. No signal in.

Voltage variations may be noted due to normal p roduction tolerances.

MEMO

SECTION 5 EXPLODED VIEWS

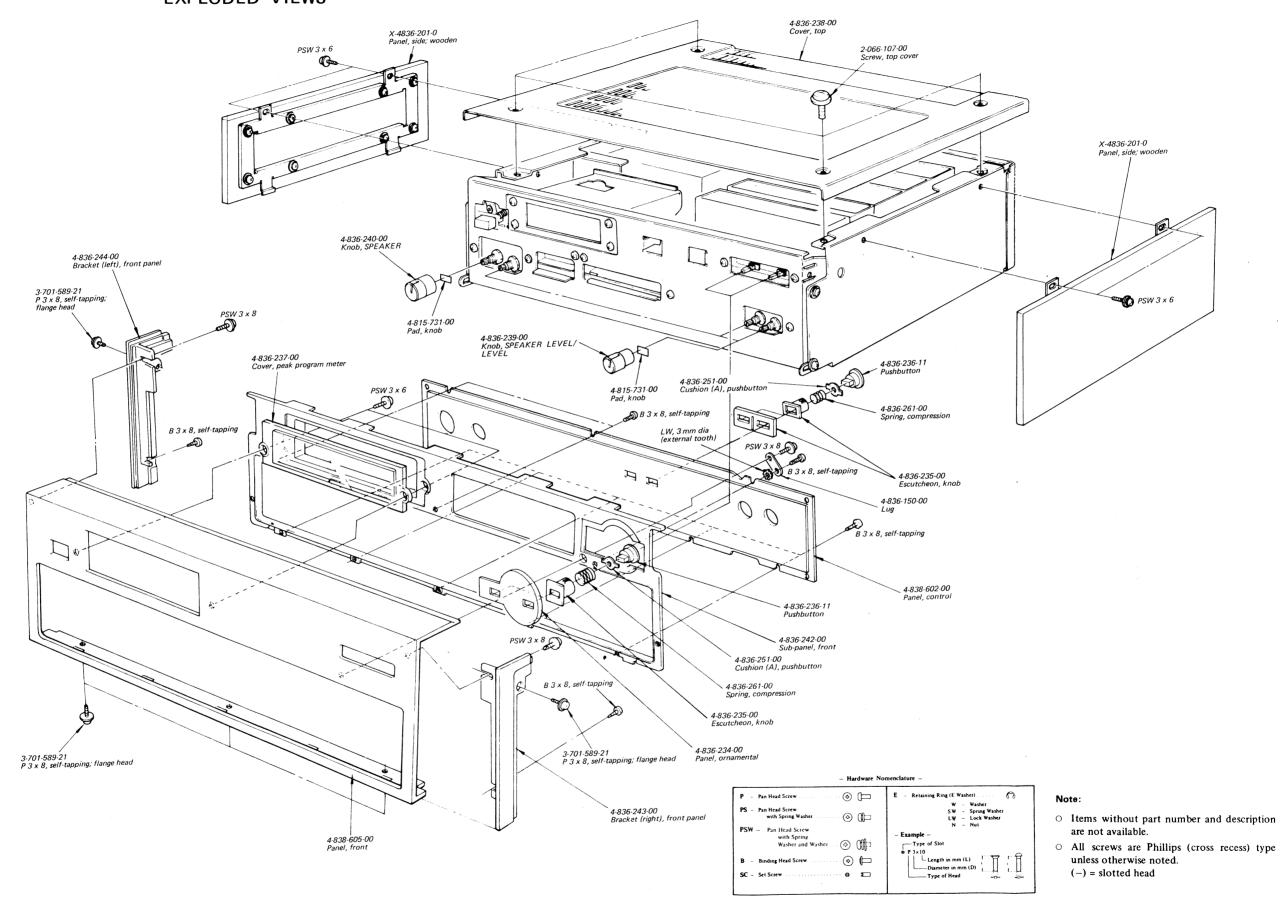
(1)

X-4836-201-0 Panel, side; wooden 4-836-244-00 Bracket (left), front panel 3-701-589-21 P 3 x 8, self-tapping; flange head 4-836-239-00 Knob, SPEAKER LEVEL/ > LEVEL 4-836-237-00 Cover, peak program meter PSW 3 x 6 H H PSW 3 x 8 3-701-89-21 P 3 x & self-tapping; flange head 3-701-589-21 P 3 x 8, self-tapping; flange head

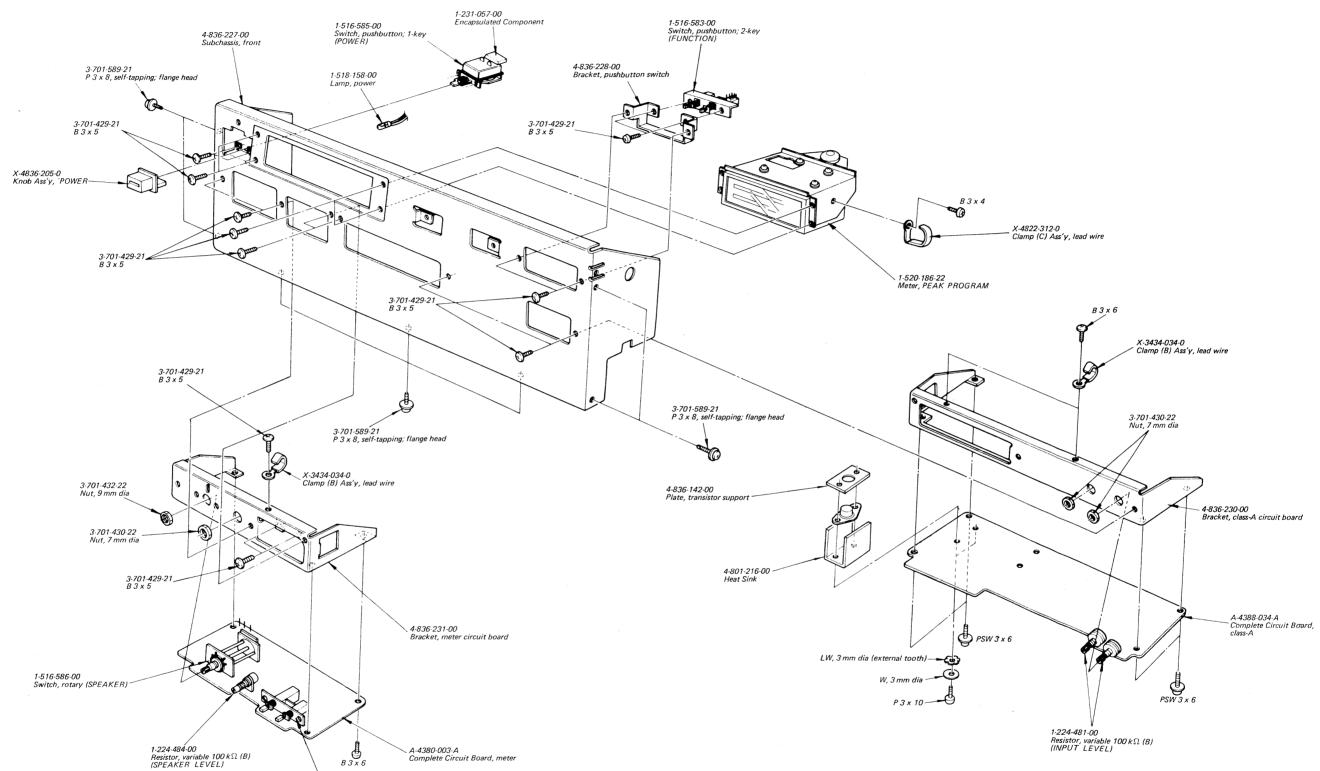
> 4-838-605-00 Panel, front

SECTION 5 EXPLODED VIEWS

(1)





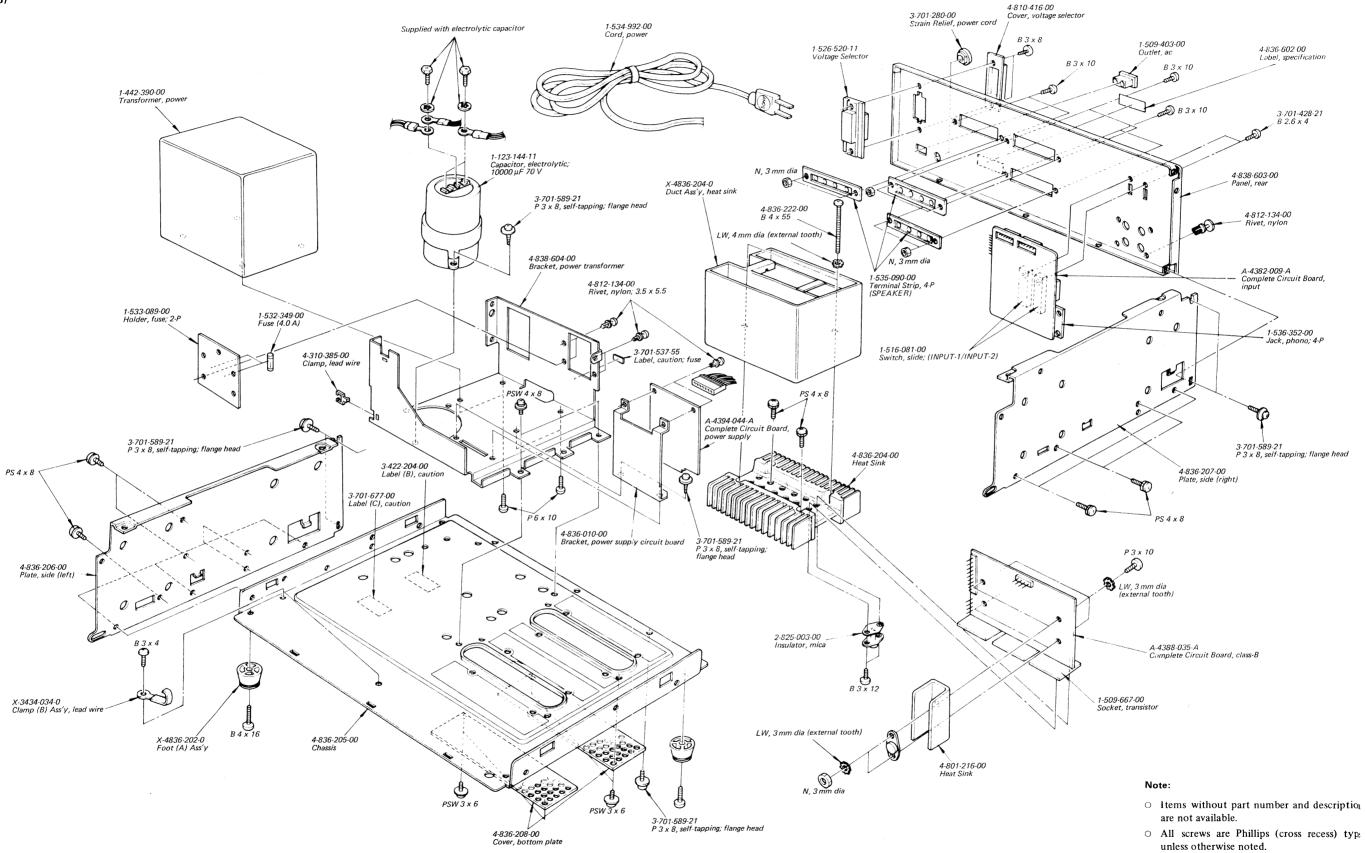


Note:

- Items without part number and description are not available.
- All screws are Phillips (cross recess) type unless otherwise noted.
 (-) = slotted head

1-516-584-00 Switch, pushbutton; 2-key (METER SENSITIVITY)





(-) = slotted head

SECTION 6 ELECTRICAL PARTS LIST

Ref. No.	Part No.	Description	Ref. No. Part No.	Description
	COMPLETE C	RCUIT BOARDS	Q713(Q763)	2SA835
			Q714(Q764)	2SC1124
	A-4380-003-A	Meter	Q715(Q765)	2SC1431
	A-4382-009-A	Input		
	A-4388-034-A	Class A amp	Q716(Q766)	2SA762
•	A-4388-035-A	Class B amp	Q717(Q767)	2SK60 (FET)
	A-4394-044-A	Power Supply	Q718(Q768)	2SK60 (FET)
	A 4354 041 A	Tower Buppay	Q719(Q769)	2SK60 (FET)
	SEMICO	NDUCTORS	Q720(Q770)	2SJ18 (FET)
		nsistors	2123(2110)	
	114	13131313	Q721(Q771)	2SJ18 (FET)
Q101(Q20)	1)	2SC634A	Q722(Q772)	2SJ18 (FET)
Q101(Q20)		2SK58 (FET)	2122(2112)	
Q102(Q20)		2SA639S	Diodes	
Q104(Q204		2SA639S		
Q105(Q20		2SA835	D101(D201)	1S1555
		20004	7101 7101	
Q106(Q20		2SC926A	D181~D184	1T22A
Q107(Q20		2SC1124	(D281~D284)	
Q108(Q20)	8)	2SC1124	7001	VD 1221
	_	222241	D301	VD-1221
Q301, Q30	02	2SC634A	D302	1T22A
Q303		2SA678	D303~D306	10D-2
Q304		2SC634A	D307, D308	1T243M
Q305		2SD291	D221	100.2
		201671	D331	10E-2
Q331		2SA671	D332	S5151
Q332		2SC1061	D333	S5151R
Q333		2SC634A	D334	10E-2
Q334		2SA678	D335	VD-1221
Q335		2SA671	D336, D337	1T243M
Q701(Q75	1)	2SA678	D701(D751)	VD-1221
Q702(Q75	(2)	2SC634A	D702(D752)	VD-1221
Q703(Q75	(3)	2SC634A	D703(D753)	1S1555
Q704(Q75	54)	2SA678	D704(D754)	5P2M
Q705(Q75		2SC634A	$D705 \sim D708$	U05E
			$(D755 \sim D758)'$	COSL
Q706(Q75	56)	2SA678		
Q707(Q75		2SA639S	D709 ~ D711	1S1555
Q708(Q75		2SC926A	$(D759 \sim D761)^{\prime}$	101000
Q709(Q75		2SC926A	D712(D762)	SH-1S
Q710(Q76		2SA639S	D713(D763)	SH-1S
			D714(D764)	1T22A
Q711(Q76	51)	2SC1124	D715(D765)	1T22A
Q712(Q76		2SA678	D716(D766)	VD-1221

Ref. No.	Part No.	Descrip	otion		Ref. No.	Part No.	Descrip	tion	
Т	RANSFORMER	AND IN	IDHCTORS		C711(C761) 1-105-661-12	0.001		
		- A.ID III	00010113) 1-105-661-12	0.001		
L701(L751)	1-407-592-00	Microin	ductor, 1.8 μ1	ц			0.033		
PT1	1-442-390-00		mer, power	11	1	1-105-685-12	0.1	400**	
	1-442-370-00	114115101	mer, power			1-105-725-12	0.1	100V	
	CARA	CITORS			C/15(C/65)) 1-105-725-12	0.1	100V	
	CAFA	CITONS			6717 (6777)	1 105 505 10			
Canacitors k	nere are in μ F, m	vlar type i	inless otherw	ica noted	1	1-105-725-12	0.1	100V	
	et = electrolytic).				C/1/(C/6/)	1-105-725-12	0.1	100V	
	mitted except fo			n so voits	C1001	1 122 144 11	10000		
01 1000 410 0	mittod except 10	receivery	tie type.		C1001	1-123-144-11	10000	70V	elect
C101(C201)	1-101-880-11	47p		ceramic		RF:	SISTORS		
C102(C202)	1-102-959-11	22p		ceramic		,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	51010113		
C181(C281)	1-121-990-11	22	16V	elect	All resistors	are in Ω . $\pm 5\%$	6 1/4 W carl	on recistors	
C182(C282)	1-105-689-12	0.22				ial type) are om			
,C183(C283)	1-105-689-12	0.22				the resistance va		k schematic	
					(k = 1000, M)		nucs.		
C301	1-121-395-11	4.7	25 V	elect	(1000, 141	- 1000 K)			
C302, C303	1-121-396-11	4.7	50 V	elect	R108(R208)	1-212-529-11	680 ±	1 %	matal avida
C304	1-121-352-11	47	10V	elect	1	1-212-685-11		1 % 1 %	metal-oxide
C305, C306	1-108-657-12	0.01	100V		i	1-206-640-11	100	2 W	metal-oxide
C307	1-121-245-11	1000	16 V	elect	ł	1-206-648-11	220	2 W	metal-oxide
					1	1-206-644-11	150	2 W 2 W	metal-oxide
C331	1-105-713-12	0.01	100 V		1 1103(R203)	1 200-044-11	130	2 W	metal-oxide
C332, C333	1-102-355-11	0.01(2p	ieces) 500V	ceramic	R336	1-212-698-11	68 k ± 1	ı ot	mantal mudda
C334	1-105-713-12	0.01	100V		R337	1-212-680-11	12 k ± 1		metal-oxide
C335, C336	1-121-941-11	470	35V	elect		1-202-525-11	10 K = 1		composition
C337	1-121-726-11	0.47	50V	elect	, , , , , , , , , , , , , , , , , , , ,	1 202 0 20 11	10	/2 **	composition
C338, C339	1-105-713-12	0.01	100 V		R725(R775)	1-206-699-11	30 k	2 W	metal-oxide
					1	1-206-700-11	33 k	2 W	metal-oxide
C340	1-121-726-11	0.47	50V	elect		1-206-676-11	3.3 k	2 W	metar-oxide
C341	1-123-083-11	47	100V	elect	1	1-217-158-11	0.47		winawa
C342	1-105-725-12	0.1	100V		l .	1-217-158-11	0.47	5 W	wirewound
					K/35(K/05)	1 217 130-11	0.47	5 W	wirewound
C701(C751)	1-121-398-11	10	25 V	elect	R740(R790)	1-217-158-11	0.47	5 W	wirewound
C702(C752)	1-121-398-11	10	25 V	elect		1-217-158-11	0.47		wirewound
C703(C753)	1-105-661-12	0.001				1-202-517-11	4.7		composition
C704(C754)	1-105-661-12	0.001			i	1-202-525-11	10		composition
	1-102-816-11	120p		ceramic	1	1 202 323-11	10	72 W	composition
		•			RT101				
C706(C756)	1-102-816-11	120p		ceramic	(RT201)	1-224-550-00	220, adjus	table (dc bal	arice adj.)
	1-121-419-11	220	6.3V	elect	RT181				
	1-102-964-11	36p		ceramic	(RT281)	1-224-250-00	2.2 k, ađju	stable (mete	r sens. adj.)
	1-102-964-11	36p		ceramic	(K1201)		-		J ,
	1-105-661-12	0.001			RT301	1-224-250-00	22k adin	etable (lama	voltage adj.)
(00)					1 11301	1 22 7 230-00	2.2 K, auju	stable (lamp	vortage auj.)

Ref. No.	Part No.	Description	Ref. No.	Part No.	<u>Description</u>
RT701 (RT751)	1-224-491-00	22 k, adjustable (dc bias adj.)	CNP1 CP1	1-534-992-00 1-231-057-00	Cord, power Encapsulated Component
RV101 (RV201)	1-224-481-00	100 k (B), variable (INPUT LEVEL)	F1, F2 J101(J201) J102(J202)	1-532-349-00 1-536-352-00	Fuse, 4 A Jack, phono; 4-p
RV102 (RV202)	1-224-484-00	100 k (B), variable (SPEAKER LEVEL)	PL301	1-518-158-00	Lamp, power
	SWI	TCHES	TM301∼ TM303	1-535-090-00	Terminal Strip (SPEAKER)
S1, S2	1-516-081-00	Slide (INPUT)	VS1	1-526-520-11	Selector, voltage
S 3	1-516-583-00	Pushbutton, 2-key (FUNCTION)		1-509-667-00	Socket, transistor
S4	1-516-584-00	Pushbutton, 2-key (METER SENS.)		1-520-186-22	Meter, peak program
S5	1-516-586-00	Rotary (SPEAKER SELECTOR)			
S6	1-516-585-00	Pushbutton (POWER)		1-533-089-00	Holder, fuse; 2-p
				1-536-354-00	Pin, terminal
		LANEOUS	Pth701 Pth751	1-800-340-00	Thermistor (Positive)
CNJ1	1-509-403-00	Outlet, ac			

ACCESSORIES AND PACKING MATERIALS			
Part No.	Description		
X-3701-029-0	Card Ass'y, warranty		
3-701-020-00	Bag, polyethylene; instruction manual		
3-701-300-00	Bag, polyethylene; unit		
3-701-730-00	Bag, polyethylene; IBM card		
3-701-742-00	Card, IBM		
3-780-480-21	Manual, instruction		
4-836-257-00	Cushion, side		
4-836-258-00	Cushion, lower		
4-836-259-00	Cushion		
4-838-607-00	Carton		